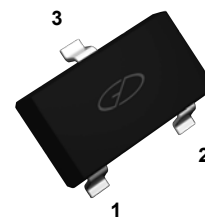


## Features

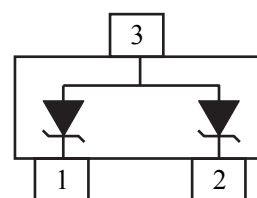
- 500W peak pulse power (8/20μs)
- Protects one/two uni-directional line(s)
- Ultra low leakage: nA level
- Operating voltage: 3.3V
- Low clamping voltage
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test Air discharge: ±30kV
  - Contact discharge: ±30kV
  - IEC61000-4-5 (Lightning) 40A (8/20μs)



SOT-23

## Applications

- Peripherals
- Industrial equipment
- Notebook computers
- Portable instrumentation
- Microprocessor based equipment
- Cell phone handsets and accessories
- Personal digital assistants (PDAs) and pagers



Schematic Diagram

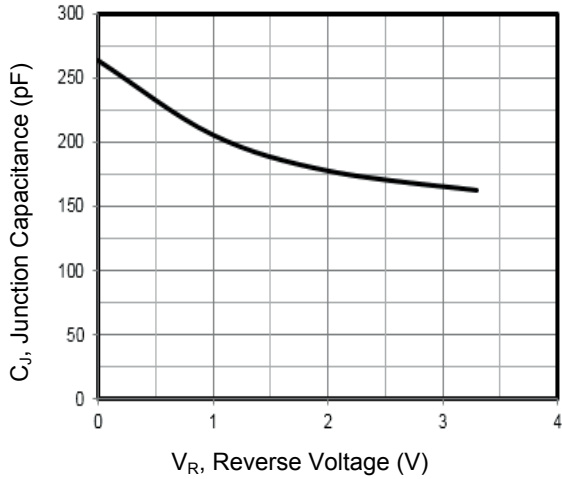
## Absolute Maximum Ratings (T<sub>A</sub>=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	P <sub>PK</sub>	500	W
Peak Pulse Current (8/20μs)	I <sub>PP</sub>	40	A
ESD per IEC 61000-4-2 (Air)	V <sub>ESD</sub>	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	T <sub>J</sub>	-55 to +125	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

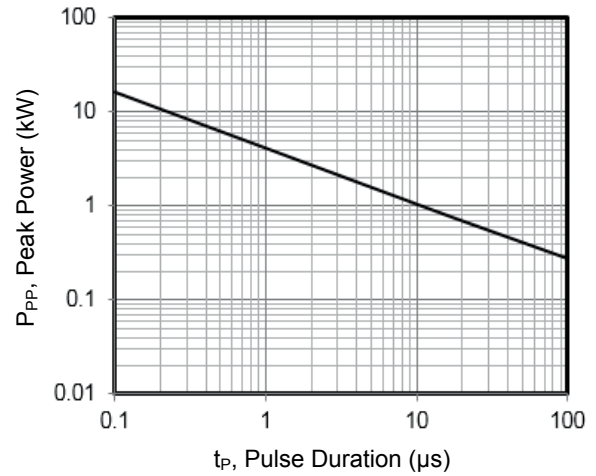
## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>	-	-	-	3.3	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> =1mA	3.5	-	-	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> =3.3V, any I/O pin to ground	-	-	0.5	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> =1A (8 x 20μs pulse), any I/O pin to ground	-	-	8	V
		I <sub>PP</sub> =40A (8 x 20μs pulse), any I/O pin to ground	-	-	12.5	V
Junction Capacitance	C <sub>J</sub>	V <sub>R</sub> =0V, f=1MHz, any I/O pin to ground	-	260	-	pF

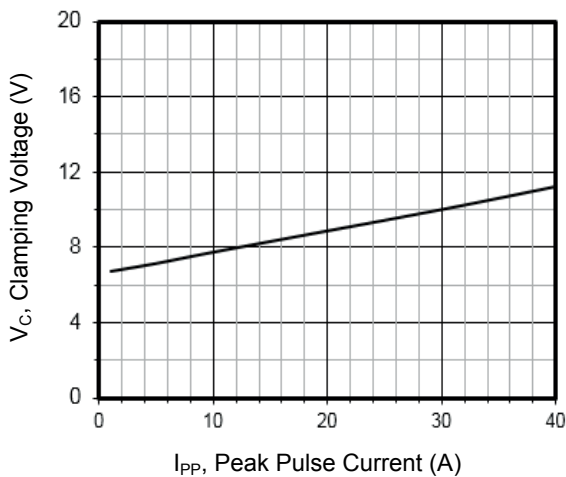
**Typical Performance Characteristics** ( $T_A=25^\circ\text{C}$  unless otherwise Specified)



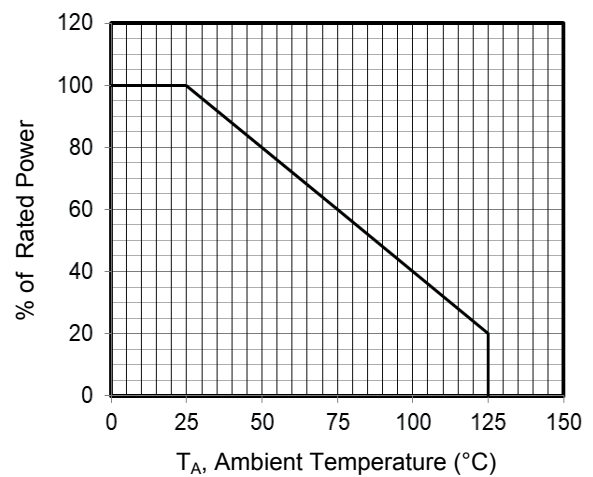
**Figure 1. Junction Capacitance vs. Reverse Voltage**



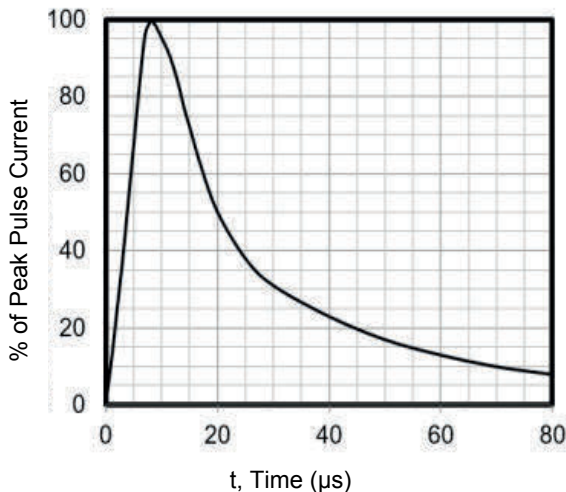
**Figure 2. Peak Pulse Power vs. Pulse Time**



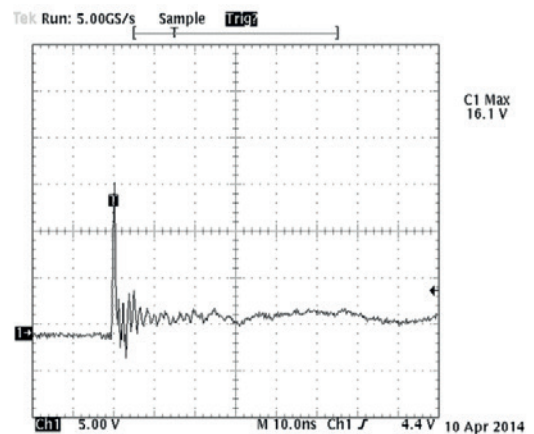
**Figure 3. Clamping Voltage vs. Peak Pulse Current**



**Figure 4. Power Derating Curve**



**Figure 5. 8 X 20µs Pulse Waveform**

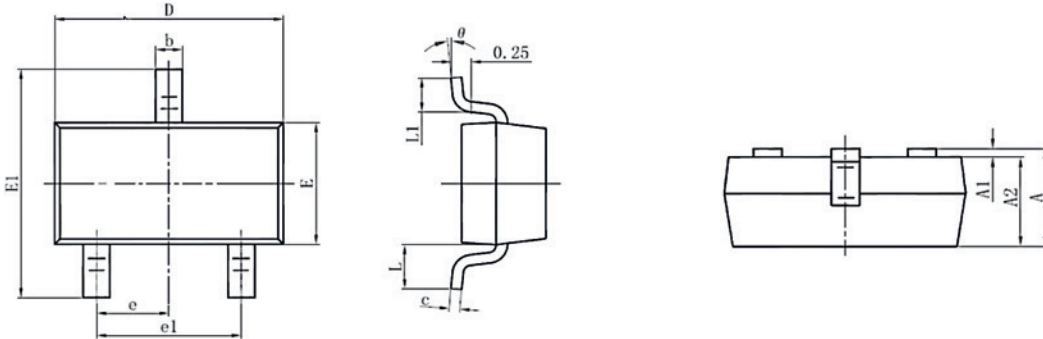


Note: Data is taken with a 10x attenuator

**Figure 6. ESD Clamping Voltage**

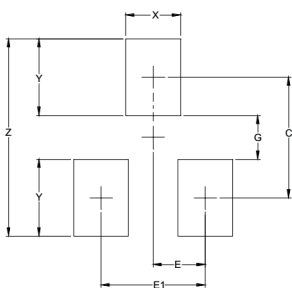
**8 kV Contact per IEC61000-4-2**

**Package Outline Dimensions (SOT-23)**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.90	1.15	0.035	0.045
A1	0.00	0.10	0.000	0.004
A2	0.90	1.05	0.035	0.041
b	0.30	0.50	0.012	0.020
c	0.08	0.15	0.003	0.006
D	2.80	3.00	0.110	0.118
E	1.20	1.40	0.047	0.055
E1	2.25	2.55	0.089	0.100
e	0.95TYP		0.037TYP	
e1	1.80	2.00	0.071	0.079
L	0.55REF		0.022REF	
L1	0.30	0.50	0.012	0.020
θ	0°	8°	0°	8°

**Recommended Pad Layout**



Symbol	Dimensions	
	Inches	Millimeters
C	0.087	2.20
E	0.037	0.95
E1	0.075	1.90
G	0.031	0.80
X	0.039	1.00
Y	0.055	1.40
Z	0.141	3.60

**Order Information**

Device	Package	Marking	Carrier	Quantity
GSEC3U2600	SOT-23	S33H	Tape & Reel	3,000pcs / Reel

For more information, please contact us at: [inquiry@goodarksemi.com](mailto:inquiry@goodarksemi.com)